

**Critical dynamics of superconducting  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$  films**K. D. Osborn<sup>1,2,\*</sup> D. J. Van Harlingen,<sup>1,2</sup> Vivek Aji,<sup>1</sup> Nigel Goldenfeld,<sup>1</sup> S. Oh,<sup>1</sup> and J. N. Eckstein<sup>1</sup><sup>1</sup>*Department of Physics, University of Illinois at Urbana-Champaign, 1110 West Green Street, Urbana, Illinois 61801-3080, USA*<sup>2</sup>*Materials Research Laboratory, 104 South Goodwin, Urbana, Illinois 61801-3080, USA*

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We report on a systematic investigation of the critical fluctuations in the complex conductivity of epitaxially grown  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$  films for  $T \leq T_c$  using a two-coil inductive technique at zero applied field. We observe the static three-dimensional (3D)  $XY$  critical exponent in the superfluid density near  $T_c$ . Linear scaling analysis close to the critical temperature yields a dynamic critical exponent of  $z \approx 2.0$  for small drive currents, but nonlinear effects are seen to be important. At  $T_c$ , a nonlinear scaling analysis also yields a 3D dynamic exponent of  $z = 2.0 \pm 0.1$ .

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**I. INTRODUCTION**

Direct observation of the scaling properties of the superconducting transition has at last become feasible due to the discovery of the cuprate superconductors. Microwave measurements in ultrapure single-crystal  $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$  (YBCO) have provided strong evidence that for accessible temperature ranges, the effective static universality class is the three-dimensional  $XY$  model (3D- $XY$ ),<sup>1</sup> where the penetration depth displayed scaling over three decades in reduced temperature. Measurements on thin films have yielded varying results: microwave measurements<sup>2</sup> report  $\nu = 1.2$ , contactless ac conductivity measurements<sup>3</sup> yield  $\nu = 1.7$  at frequencies up to 2 GHz, and dc conductivity in finite magnetic fields<sup>4</sup> give  $\nu = 0.9-1.0$ . While none of these agree with the 3D- $XY$  scaling behavior, it is widely believed that the results on pure single crystals are indicative of the intrinsic critical fluctuations of the superconducting transition.

Transport measurements have probed the dynamics of the critical fluctuations, which are characterized by the value of the dynamic critical exponent  $z$  describing how the relaxation time  $\tau$  scales with the correlation length  $\xi$ :  $\tau \sim \xi^z$ . However for YBCO, experiments have not yielded a consistent picture. For example, longitudinal dc-resistivity measurements<sup>5</sup> yield  $z = 1.5 \pm 0.1$  in magnetic fields up to 6 T, while microwave conductivity measurements<sup>2</sup> are consistent with  $z = 2.3-3.0$ . Still larger values for the dynamic exponent ranging from  $z = 5.6$  to  $z = 8.3$ , reminiscent of glassy dynamics, have also been seen in resistivity measurements<sup>3,4</sup> in thin films. These large values of  $z$  strongly suggest that disorder plays a dominant role in these thin films, and this may explain why their observed static critical behavior differs from that of the best single crystals.

Critical fluctuation results on  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$  (BSCCO) are even more dissimilar, partially due to highly anisotropic fluctuations. The complex conductivity of underdoped BSCCO films measured at terahertz frequencies was found to agree with a Kosterlitz-Thouless-Berezinskii (KTB) model with diffusive dynamics.<sup>8,9</sup> In previous work on BSCCO crystals a nonlinear transport study found 2D critical behavior with an anomalous dynamic exponent of  $z \approx 5.6$  and no crossover to 3D behavior.<sup>6</sup> The 3D universal phase angle of the complex conductivity deduced from the magnetic susceptibility of BSCCO epitaxial films and crys-

tals has even yielded larger values of  $z$ .<sup>7</sup> Only dc fluctuation conductivity measurements in BSCCO (Ref. 10) find relaxational dynamics,  $z \approx 2.0$ , assuming a 3D- $XY$  static exponent,  $\nu \approx 2/3$ , in agreement with recent theoretical work that predicts that  $z \approx 2.0$  in 3D.<sup>11</sup> These results indicate the lack of consensus on the true nature of the dynamic fluctuations representative of the superconducting transition, which is the primary motivation of the present investigation. While a large value of the dynamic exponent ( $z > 2$ ) can be understood as disorder effects, only the presence of a previously undetected collective mode coupled to the superfluid density would lead to  $z \approx 1.5$  in 3D, just as it occurs in superfluid  $\text{He}^4$ .<sup>12</sup>

In this paper we provide results on the critical fluctuations in high quality epitaxially grown BSCCO films. We have measured the  $ab$ -plane complex conductivity with a two-coil inductive technique at zero applied magnetic field ( $H = 0$ ), described in Sec. II. Our measurements, presented in Sec. III, indicate that the critical fluctuations in BSCCO films are consistent with the 3D- $XY$  critical fluctuation model, rather than a KTB transition within the layers. This contrasts with earlier studies using this technique on YBCO, which have reported KTB critical<sup>13</sup> and mean-field<sup>14</sup> fluctuations. In Sec. IV, we estimate the temperature intervals in which possible crossovers to 2D fluctuations can occur, due to either decoupling of the bilayers or the thin film behaving as a 2D system with a large  $c$ -axis correlation length. We find that our measurements should indeed be well described by anisotropic 3D- $XY$  critical fluctuations. In Sec. V, we provide a crossover analysis of the approach to the critical point, and examine the approach to a universal phase angle. In particular, we predict the qualitative forms of the variations with temperature and frequency. These are in agreement with our measurements, but contrast earlier results which report very different values of the static and dynamic critical exponents than those reported here. Analysis of the phase angle of the film response using linear-response theory in the critical region, which yields a dynamic exponent of  $z = 2.0$ , is presented in Sec. VI. However, the breakdown of linear-response theory becomes important near the transition temperature  $T_c$ , so that the analysis is complicated by the need to extract the superfluid density from the measured mutual inductance by an approximate inversion technique. Our analysis shows that the determination of  $z$  purely from linear-response theory is contami-

nated by nonlinear effects, and at probe currents that are too large the effective value of  $z$  inferred can be as low as 1.5. To circumvent this problem, we derive in Sec. VII a nonlinear scaling law obeyed by the raw measured mutual inductance at  $T_c$  (i.e., without the need for a data inversion) and extract the dynamic exponent directly from the mutual inductance. In agreement with the linear-response analysis, we again obtain  $z \approx 2.0$ . Section VIII summarizes our conclusions.

## II. SAMPLES AND EXPERIMENTAL SETUP

We have measured several high quality oxygen-doped BSCCO films, grown by molecular-beam epitaxy on SrTiO<sub>3</sub> substrates and analyzed *in situ* by reflection high-energy electron diffraction.<sup>16</sup> The BSCCO films are nominally oriented along the  $c$  axis, with unit-cell thickness of  $d = 15.4$  Å. Atomic force microscopy (AFM) images of similar BSCCO films reveal a rms roughness of 5 Å primarily due to single unit-cell step height variation over the surface. The rms roughness of the substrates are  $\approx 1.5$  Å.

The inductively measured  $T_c$  from several films of different dopings was fit to the empirical formula  $T_c = T_{c,max} [1 - 82.6(p - 0.16)]^2$ , to determine the hole doping per Cu,  $p$ .<sup>15</sup> The two branches of the formula are distinguished by the relative low-temperature superfluid density, which is known to increase monotonically through optimal doping ( $p = 0.16$ ). Films A, B, and C have  $n = 21$ , 40, and 60 unit cells, respectively, and are grown on square 10 and 14 mm substrates. Film A is overdoped at  $p \approx 0.19$ , while films B and C are slightly overdoped and underdoped, respectively. We estimate that a doping gradient in the samples introduces a experimental temperature broadening of 0.15 K near  $T_c$ .

To obtain the  $ab$ -plane complex conductivity, we employ a two-coil inductive technique. The mutual inductance of two coaxial coils is measured with a film placed in between and normal to the axis of the coils. An ac current is applied through the drive coil; a second coil, attached to a large input impedance lock-in amplifier, measures the fields produced by the drive coil and the screening currents in the film. The coils have 135 turns and an average radius of 1.5 mm. The drive coil is placed 0.35 mm above the film so that at a current of  $I = 50$  μA rms, the applied ac magnetic field is  $< 0.1$  G normal to the film. Measurements are performed in a He<sup>4</sup> continuous-flow Dewar, which allows the temperature of the film to be controlled without significant heating from the drive coil. The sample temperature is monitored by a Si diode attached to the back side of the substrate.

The complex conductivity  $\sigma = \sigma_1 - i\sigma_2$  of each film is calculated from the mutual inductance using the exact analytical expression for an infinite diameter film<sup>17</sup> and a numerical inversion technique similar to that of Fiory *et al.*<sup>18</sup> The method of Turneure *et al.*<sup>19</sup> is employed to correct for film diameter effects prior to calculating the in-plane complex conductivity. The measured penetration depth  $\lambda_{ab} = (\mu_0 \omega \sigma_2)^{-1/2}$  is independent of the measurement frequency from  $f = 10$ –100 kHz below the transition temperature, where the dissipation is small ( $\sigma_1 \ll \sigma_2$ ). To analyze the critical fluctuations, we study the complex superfluid density per CuO bilayer,  $\rho = i\sigma\omega d\Phi_0^2/(4\pi^2 k_B)$ , where  $\Phi_0$  is the

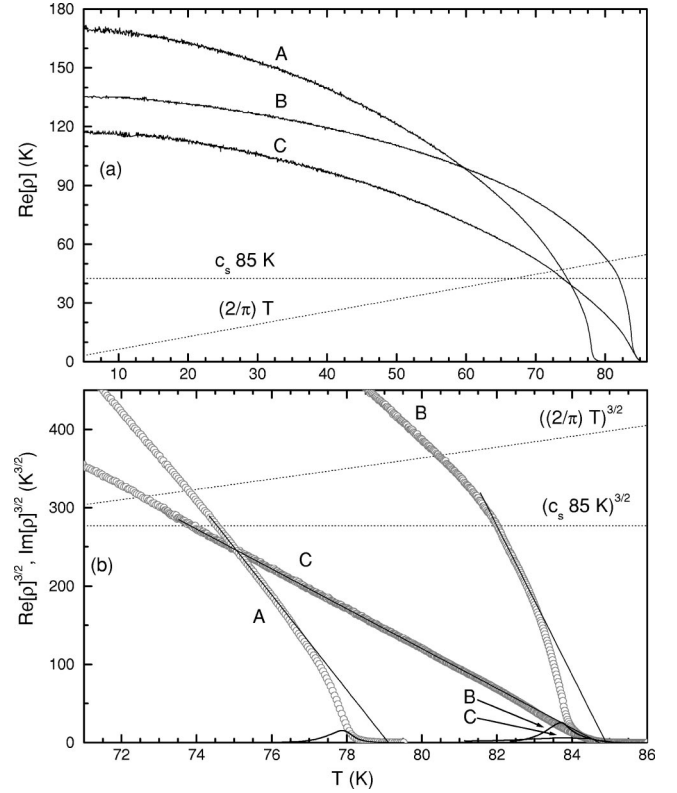


FIG. 1.  $\text{Re}[\rho]$  [panel (a)] and  $\text{Re}[\rho]^{3/2}$  [panel (b)], as a function of temperature for films A–C.  $\rho = (c_s/85 \text{ K})$  is the predicted crossover to 3D-XY critical behavior and  $\rho = (2/\pi)T$  is the KTB critical superfluid density for an isolated bilayer.

superconducting flux quantum.<sup>20</sup> The real part of this quantity,  $\text{Re}[\rho]$  has units of temperature and sets the energy scale for critical fluctuations. In Fig. 1(a),  $\text{Re}[\rho]$  obtained at  $f = 80$  kHz and  $I = 40$  μA is plotted for films A–C. At 5 K, films A, B, and C, have penetration depths of 235, 265, and 285 nm, respectively. Note that film A, which is overdoped, has a smaller low temperature penetration depth than films B and C. All films exhibit a  $T^2$  component to the superfluid density at low temperatures, however the normal state resistivity extrapolated to zero temperature is nearly zero in optimally doped films, indicating the crystalline films have very few impurities.

## III. STATIC CRITICAL BEHAVIOR

In Figs. 1(a) and 1(b) a power of  $\rho = \text{Re}[\rho]$  and  $2T/\pi$  is shown to be located where we would expect the KTB transition for a noninteracting bilayer,  $\rho = 2T/\pi$ .<sup>21</sup> We observe no such drop in the superfluid density at this temperature in our films. The films instead show that coupling among the bilayers induces an anisotropic 3D transition, precluding a KTB transition in the bilayers. At the transition temperature of an isolated bilayer  $T = \rho\pi/2$ , however, the measured superfluid density has been renormalized from the mean-field value by quasi-2D fluctuations.

The mean-field behavior, expected at low temperatures, crosses over to the 3D-XY behavior as the critical temperature is approached from below. In layered systems, the

3D-XY behavior is exhibited once the  $c$ -axis correlation length exceeds the interlayer spacing  $d$ ; i.e., when  $\rho(T) = c_s T_c$ , where  $c_s \approx 0.5$  and  $\rho = \text{Re}[\rho]$ .<sup>1</sup> In Fig. 1(b), the data from Fig. 1(a) are plotted as  $\text{Re}[\rho]^{3/2}$  near the critical regime. Also shown in Figs. 1(a) and 1(b) is the corresponding power of  $c_s T_c$  to locate the onset of 3D-XY behavior. The static 3D-XY model gives  $\rho \sim \xi^{-1} \sim |T - T_c|^\nu$ , where  $\nu \approx 2/3$ . We observe that  $\text{Re}[\rho]^{3/2}$  varies linearly in temperature for  $\rho(T) \leq c_s T_c$  indicating a 3D-XY, rather than mean-field ( $\rho \sim |T - T_c|$ ), behavior. At our measurement current (40  $\mu\text{A}$ ), we observed an absence of frequency dependence below the dissipation peak over the temperature range of the fit. In film  $C$ , the linear regime extends as far as 7 K below 82 K. The linear fits extrapolate to  $T_c = 79.1$  K, 84.9 K, and 84.7 K for films  $A$ ,  $B$ , and  $C$ , respectively.

Although our static scaling analysis is carried out at temperatures and at a drive current for which there is no discernible frequency dependence, at higher temperatures we observe variations with both drive current and frequency. This is apparent in Fig. 2, for which larger currents are used on film  $B$  with 40 layers. Film  $C$ , with 60 layers, exhibited a weaker dependence over the same frequencies and currents. Since the superfluid density depends on frequency and current at higher temperatures, the superfluid density scales as  $\rho \sim \xi^{2-D} f(\omega \xi^z, E \xi^{1+z})$ , where  $E$  is the amplitude of the electric field. Only in the critical regime where the data are independent of both frequency and electric field can one expect to see the linear-response scaling behavior and extract the exponent  $\nu$ . At higher temperatures where we observe nonlinear behavior as well as frequency dependence, the data are still consistent with the 3D-XY fluctuations, and we can extract  $z$ . In Sec. VI we analyze the phase angle in terms of linear response theory, but a nonlinear scaling analysis is required for completeness and is given in Sec. VII.

#### IV. DIMENSIONALITY OF THE STATIC FLUCTUATIONS

When the superfluid density is less than one half of the 3D crossover,  $\rho(T) < (1/2)c_s T_c$ , we observe a drop in the superfluid density from the static scaling value. Although this could be interpreted as a crossover to 2D behavior, we do not believe this to be the case in our films since the drop is observed to be current as well as frequency dependent (see Fig. 2). Notice that the superfluid density does drop more rapidly than expected from the 3D-XY model as the frequency is decreased for a given drive current, but does so more slowly as the current is decreased at fixed frequency. While the former might lead one to conclude that the anisotropic 3D-XY behavior is no longer valid in the static limit, the latter would imply the opposite. More accurate measurements are needed at low frequency and currents to establish unambiguously the true nature of the static limit. Nevertheless, the trend with decreasing current, coupled with the phase angle dependence discussed in the following section, is consistent with 3D-XY behavior. Another putative crossover to 2D behavior is expected when  $\xi_c$  becomes as large as the film thickness  $h$ . The 3D-XY scaling implies that this occurs at a temperature  $T^*$  which is 0.05 K, 0.01 K, and 0.02 K below the transition temperature for films  $A$ ,  $B$ , and  $C$ ,

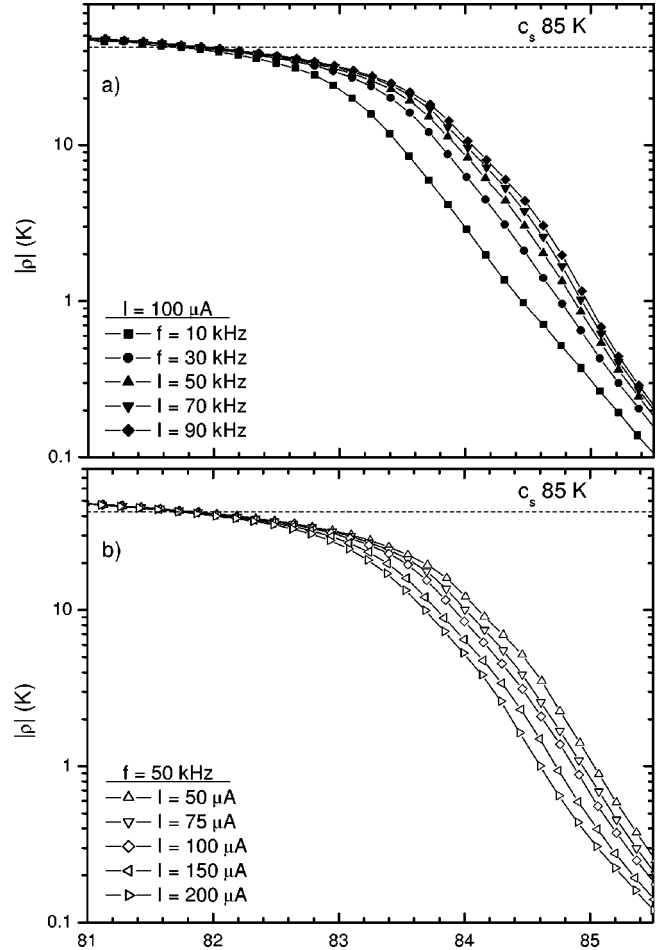


FIG. 2.  $|\rho|$  in film  $B$  taken at a series of frequencies [panel (a)] and drive currents [panel (b)].

respectively. This implies that the region of pure 2D fluctuations is too small to be resolved in our data and therefore we expect 3D fluctuations to dominate.

#### V. CROSSOVER PHENOMENA IN THE LINEAR PHASE ANGLE NEAR $T_c$

Since the experiments are performed at finite frequency, it is important to consider whether or not the correct asymptotic behavior is being probed and what conclusions can be drawn from the observed behavior. We begin with the superfluid density, within linear response, written as

$$\rho = (t^{-\nu})^{2-D} f_1(\omega t^{-\nu z}), \quad (1)$$

where  $t = |T - T_c|/T_c$  and  $f_1$  is a scaling function. In the limit of  $t \rightarrow 0$  ( $T \rightarrow T_c$ ), the  $t$  dependence must cancel out of the expression for  $\rho$ , which implies that the asymptotic behavior of the scaling function  $f_1(x) \sim x^\theta$  as  $x \rightarrow \infty$  where  $\theta = (2 - D)/z$ . For  $t \neq 0$ , we can write

$$\rho = (i\omega)^{(D-2)/z} f_2(t\omega^{-1/\nu z}), \quad (2)$$

where the scaling function  $f_2(y) = \text{const}$  as  $y \rightarrow 0$ . We now ask what behavior we should observe as  $\omega \rightarrow 0$  for  $t \neq 0$ . For



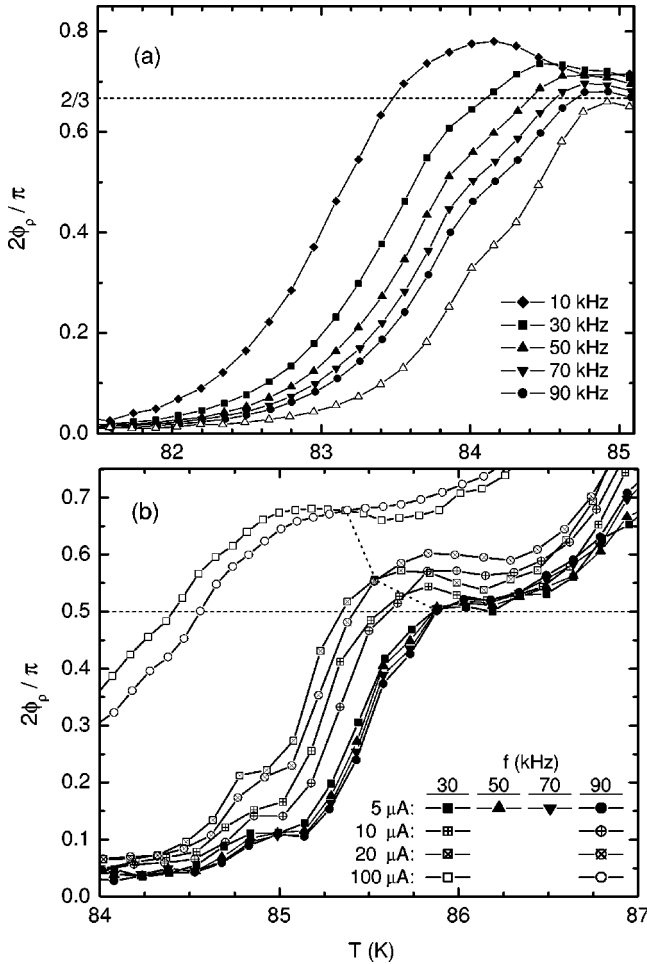


FIG. 3. Normalized phase angle  $2\phi_\rho/\pi$  of the superfluid density extracted from linear-response theory. Panel (a):  $2\phi_\rho/\pi$  in film *B* taken at  $I=100\ \mu\text{A}$  (filled symbols) at a series of frequencies and  $I=50\ \mu\text{A}$  for  $f=50\ \text{kHz}$  (unfilled triangles). Panel (b):  $2\phi_\rho/\pi$  in film *C* for a given table of frequencies and drive currents.

$\omega \rightarrow 0$  at  $t=0$ , we should see the critical-point behavior. For  $t/\omega^{1/\nu z} \ll 1$  we are probing the  $y \sim 0$  regime of the scaling function  $f_2(y)$  and expect to see asymptotic scaling behavior. If  $t/\omega^{1/\nu z} \gg 1$  we are probing the  $y \rightarrow \infty$  regime of the argument of  $f_2$  and do not expect to see the scaling behavior. Thus at a finite  $t_0$ , for  $\omega \gg t_0^{4/3}$  we would observe critical behavior while for  $\omega \ll t_0^{4/3}$  we would not. We have used the critical exponents  $\nu=2/3$  and  $z=2$  for specificity, but the argument does not rely on these precise values. Note that, as is generally the case with crossover, the behavior of the superfluid density away from the critical point at finite frequencies is not universal except in the large frequency limit—a result that is sometimes found to be surprising, but which follows from a generic crossover analysis of relevant variables.<sup>22</sup> This predicted low-frequency behavior is consistent with our data where we observe the critical phase angle in Fig. 3(b) and yet we do not observe scaling below  $T_c$ . More importantly, this is also consistent with the nonlinear scaling observed at  $T_c$  in Sec. VII. Away from  $T_c$  an asymptotic scaling regime is demonstrated in the microwave measurements of Booth *et al.*<sup>2</sup>

## VI. DYNAMIC CRITICAL BEHAVIOR AND THE BREAKDOWN OF LINEAR RESPONSE THEORY

Next we study the phase of  $\rho$ ,  $\phi_\rho$ , close to the transition temperature. The frequency dependence of  $2\phi_\rho/\pi$  for film *B* measured at  $I=100\ \mu\text{A}$  is shown in Fig. 3(a). Within linear-response theory, the phase angle is independent of frequency at the critical temperature and is given by  $\phi_\rho(T_c) = \pi/(2z)$  in three dimensions, where  $z$  is the dynamic critical exponent.<sup>23</sup> In Fig. 3(a) we notice that the curves for different frequencies seem to approach a phase angle consistent with a dynamic exponent of  $z \approx 1.5$  and  $T_c = 84.9\ \text{K}$ . When repeated at a smaller value of the current,  $I=50\ \mu\text{A}$ ,  $\phi_\rho(T_c)$  is smaller, as shown. Since the constant phase angle is a result from linear-response theory, the estimate of the dynamic exponent from the data is expected to be more accurate at smaller currents.

This is indeed seen in the current dependence of the phase angle at different frequencies for film *C*. In Fig. 3(b),  $2\phi_\rho/\pi$  is shown for a set of frequencies and currents. As the current is lowered, the frequency independent phase angle shifts to lower values. At  $20\ \mu\text{A}$ ,  $10\ \mu\text{A}$ , and  $5\ \mu\text{A}$ , this phase angle is  $0.57\pi/2$ ,  $0.54\pi/2$ , and  $0.51\pi/2$ , respectively. This suggests that  $z \approx 2.0$  in film *C* and the result of  $z \approx 1.5$  from film *B* is an artifact of the large current used in the measurement. With this analysis, the thickest film (*C*) exhibits the best estimate of the critical phase angle, the film with intermediate thickness (*B*) provides evidence for similar behavior, but the thinnest film does not show a critical phase angle. Due to the crossover phenomena discussed in the preceding section, the behavior of the phase angle away from  $T_c$  is not universal at low frequencies, but we can still infer the dynamic critical exponent from the critical phase angle at  $T_c$  which is indeed universal.

Both the phase angle and the superfluid density are found to be dependent on the drive current near  $T_c$ . In the limit of smaller currents, the frequency independent critical phase angle does indeed yield a dynamic exponent of  $z \approx 2.0$ . This is a result consistent with the presence of 3D fluctuations. This is also consistent with the behavior of the superfluid density with decreasing current at fixed frequency, where it is seen to approach the asymptotic static scaling law. Furthermore, the smooth evolution of the phase angle suggests that the crossover to the 2D regime near  $T^*$  is not resolved in our experiment. Nevertheless, considering that nonlinear scaling and dimensional crossover is expected close to  $T_c$ , we now proceed to analyze the nonlinear response to get a more accurate determination of the dynamic exponent.

## VII. NONLINEAR SCALING AT THE SUPERCONDUCTING TRANSITION

The field equation governing the vector potential  $\vec{A}$  is

$$\nabla^2 \vec{A}/\mu_0 = -\vec{J}_d - h\delta(z)\sigma\vec{E}, \quad (3)$$

where  $\vec{J}_d$  is the current density in the drive coil,  $\sigma$  is the conductivity of the superconducting film, and  $\vec{E}$  is the electric field. For the geometry of the setup,

$$\vec{J}_d = I_d \delta(r - r_c) \delta(z - z_c) \hat{\phi} \quad (4)$$

in cylindrical coordinates, where  $I_d$  is the drive current,  $r_c$  is the radius of the drive coil, and  $z_c$  is the distance from the film to the drive coil.<sup>17</sup> For an anisotropic system, in the critical regime, the superfluid density  $\rho$  scales as

$$\rho \sim i\omega\sigma \sim \xi_{ab}^{3-D} \xi_c^{-1} f(i\omega \xi_{ab}^z, E \xi_{ab}^{1+z}), \quad (5)$$

where  $\xi_{ab}$  and  $\xi_c$  are the correlation lengths parallel and perpendicular to the CuO bilayers, and  $f$  is a scaling function. We can rewrite the field equation as

$$\nabla^2 A = -\mu_0 I_d \delta(r - r_c) \delta(z - z_c) - h \xi_{ab}^{3-D} \xi_c^{-1} f(\omega \xi_{ab}^z, A \xi_{ab}) A \delta(z), \quad (6)$$

where we have used the scaling form for the complex conductivity. Since the scaling function is written in terms of dimensionless variables we can nondimensionalize the equation by recasting it in terms of  $A \xi_{ab}$ ,  $\omega \xi_{ab}^z$ ,  $r/h$ , and  $I_d \xi_{ab}$ . The solution then takes the form

$$A i \omega \xi_{ab}^{1+z} = G(i\omega \xi_{ab}^z, i\omega \xi_{ab}^{1+z} I_d, h^2 \xi_{ab}^{3-D} \xi_c^{-1} \Lambda^{-1}, r/h), \quad (7)$$

where  $G$  is a function that can be determined by solving the full nonlinear field equation and  $\Lambda$  is the thermal length given by  $\Phi_0^2 / (4\pi\mu_0 k_B T)$ . So far all we have done is to use the scaling form for the superfluid density and looked for a generic solution of a differential equation by identifying all the nondimensional variables. For a given geometry of the experiment the right-hand side of Eq. (7) is a function of three variables. One can further simplify the expression if we realize that there exists a regime  $|T - T_c| < T^*$  where we are governed by the limit where  $\xi_c = h$ . This allows us to eliminate one of the three terms as follows. Close to  $T_c$ , using the 3D-XY behavior of the correlation length and the definition of  $T^*$ , we can rewrite  $h^2 \xi_{ab}^{3-D} / \xi_c$  as

$$h^2 \xi_{ab}^{3-D} / \xi_c = h |1 + (T - T^*) / (T^* - T_c)|^\nu. \quad (8)$$

For a temperature range  $|T - T^*| \ll |T^* - T_c|$ ,  $h^2 / \xi_c \approx h$ . Thus, for temperatures within 0.05 K, 0.02 K, and 0.01 K of  $T^*$  for films A, B, and C respectively, this approximation is valid, and the field in Eq. (7) is a function of only two variables for a given geometry. Thus one can now perform the standard data collapse at  $T_c$  of the measured mutual inductance to obtain the dynamic exponent. In this regime we can eliminate  $\xi_{ab}$  from Eq. (7) so that

$$A = \omega^{1/z} \tilde{G}(I_d \omega^{-1/z}, h \Lambda^{-1}, r/h). \quad (9)$$

The mutual inductance  $M$  is related to the vector potential at the pickup coil and scales as

$$M \sim A \omega^{-1/z} \sim \tilde{G}(I_d i \omega^{-1/z}). \quad (10)$$

Within the resolution of our data, any data collapse observed is a 3D phenomena starting to crossover to the asymptotic 2D scaling. The reason for this is that the solution [Eq. (7)] depends on a number of variables, but sufficiently

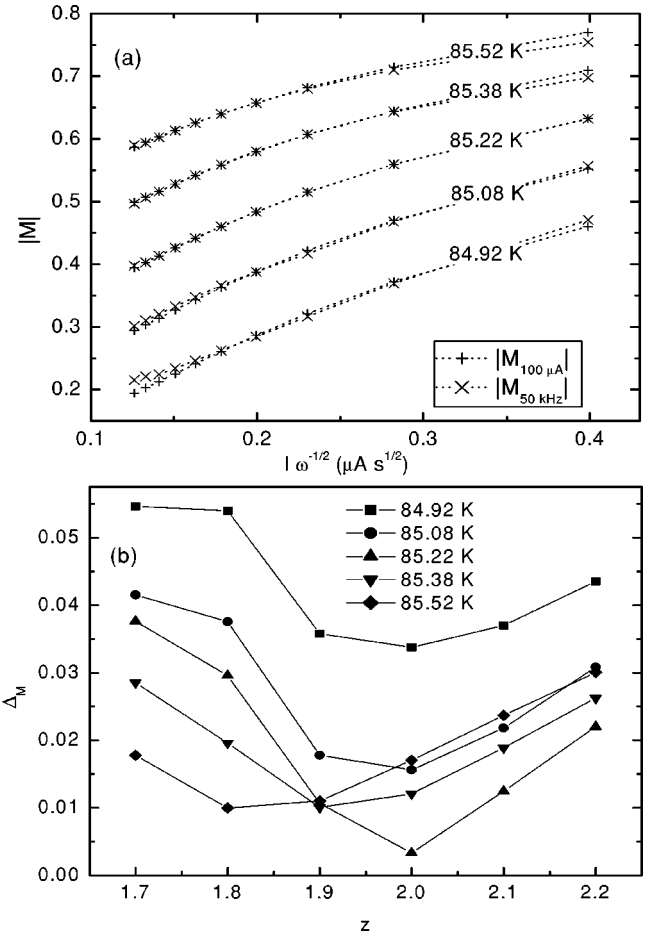


FIG. 4. Panel (a):  $|M|$  measured at  $I = 100 \mu\text{A}$  and  $f = 50 \text{ kHz}$  vs the scaling variable  $I\omega^{-1/2}$ . Panel (b): Scaling error at different temperatures vs  $z$ .

close to  $T_c$  there exists a regime wherein the mutual inductance is only a function of one scaling variable. If we do not observe any data collapse we would conclude that we are never in the regime where the approximation  $h^2/\xi_c \approx h$  is valid. It is indeed true that the elimination of the dependence of  $\xi_{ab}$  in Eq. (7) is possible only at  $T_c$  and need not hold in the entire regime where the crossover occurs. It is tempting to interpret the experimental results in terms of a 2D system. Our data, on the other hand, are unable to resolve the crossover regime, and yet do exhibit data collapse (see Fig. 4). This suggests that the temperature at which we observe data collapse lies in the crossover regime, but is not necessarily the true  $T_c$ . From our analysis we conclude that the  $T_c$  is within 0.02 K of the temperature at which we observe data collapse for films B and C. We now look for data collapse of our data measured by varying frequency, current, and temperature. Notice that the value of the exponent  $\nu$  is required only to establish the regime of validity of the approximation and is not necessary to extract the dynamic exponent from data collapse at  $T_c$ .

For the scaling analysis at  $T_c$ , the mutual inductance at fixed frequency  $M_f$  was compared to the mutual inductance at fixed current  $M_I$ . For convenience,  $|M(T)|$  is normalized to unity above  $T_c$ . Values of  $M_f(M_I)$ , were measured at

12.5  $\mu\text{A}$  (10 kHz) intervals for a set of fixed temperatures. Then values of  $|M_f|$  were compared with values of  $|M_I|$  taken at the same temperature by fitting the raw data of  $|M_f|$  to a polynomial and selecting points with the values of  $I\omega^{-1/z}$  equivalent to those of  $|M_I|$ . In Fig. 4(a)  $|M_f|$  and  $|M_I|$  for film *B* are plotted versus  $I\omega^{-1/2}$  for a series of temperatures. The best data collapse of the curves appear at  $z=2.0$  and  $T=85.22$  K. The error in the scaling  $\Delta_M$  is shown in Fig. 4(b) for different temperatures and values of  $z$ . This is obtained from  $\Delta_M^2 = \sum (|M_f| - |M_I|)^2$ , where the sum runs over the ten values of  $I\omega^{-1/z}$  measured for  $|M_I|$ . The lowest error value indicates  $z=2.0\pm 0.1$  and  $T=85.2\pm 0.1$  K. A similar analysis for the film *C* yields  $z=1.8\pm 0.2$  and  $T=85.9\pm 0.2$  K, which is also consistent with  $z=2.0\pm 0.1$ . The transition temperature of film *B* is  $T_c=85.2\pm 0.1$  K, while for film *C* it is  $T_c=85.9\pm 0.2$  K. These values of  $T_c$  are close to those obtained with the phase angle measurements.

In Fig. 4(b), the evolution of the error for a fixed trial  $z$  also suggests that the dynamic exponent observed is indeed due to 3D fluctuations. Note that as the temperature is increased for  $z=2.0$ , the error decreases, approaching the best fit (i.e., data collapse), and then increases again. Within the resolution of the data, we never observe any change to the 2D regime. In other words, the approximation that allowed us to look for the data collapse is indeed supported by the

behavior of the mutual inductance.

### VIII. CONCLUSIONS

The superfluid density in BSCCO films with different thicknesses has been measured and shown to be consistent with the predictions of the 3D-XY model. The dynamic scaling exponent has been obtained by performing both a linear and nonlinear scaling analysis. While the linear scaling analysis did yield a 3D dynamic exponent of  $z\approx 2.0$ , nonlinear effects needed to be studied to get an accurate determination. This is evident from the current dependence of the critical phase angle of the superfluid density. A 3D nonlinear scaling analysis also yields a dynamic exponent of  $z=2.0\pm 0.1$ .

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